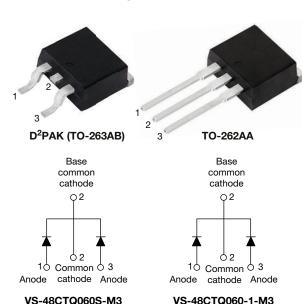


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High Performance Schottky Rectifiers, 2 x 20 A



PRIMARY CHARACTERISTICS					
I _{F(AV)} 2 x 20 A					
V_{R}	60 V				
V _F at I _F	0.58 V				
I _{RM} typ.	89 mA at 125 °C				
T _J max.	150 °C				
E _{AS}	13 mJ				
Package D ² PAK (TO-263AB), TO-262A					
Circuit configuration	Common cathode				

FEATURES

- 150 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High frequency operation



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	SYMBOL CHARACTERISTICS VALUES UNITS							
I _{F(AV)}	Rectangular waveform	40	Α					
V _{RRM}		60	V					
I _{FSM}	t _p = 5 μs sine	1000	Α					
V _F	20 A _{pk} , T _J = 125 °C (per leg)	0.58	V					
TJ	Range	-55 to +150	°C					

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-48CTQ060S-M3 VS-48CTQ060-1-M3 UNITS						
Maximum DC reverse voltage	V_{R}	60	V			
Maximum working peak reverse voltage	V_{RWM}	00	V			

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ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum average	per leg				20			
forward current See fig. 5	per device	I _{F(AV)}	50 % duty cycle at T _C = 111 °C	40				
Maximum peak one cycle		_	5 μs sine or 3 μs rect. pulse	Following any rated load	1000	Α		
non-repetitive surge current per leg See fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	260			
Non-repetitive avalanche energy per leg		E _{AS}	$T_J = 25$ °C, $I_{AS} = 1.50$ A, L = 11.5 mH		13	mJ		
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.50	Α		

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		20 A	- T _{.1} = 25 °C	0.61	V	
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	40 A	1j=25 C	0.83		
See fig. 1	VFM (1)	20 A	T _{.1} = 125 °C	0.58		
		40 A	- IJ = 125 C	0.75		
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	2	mA	
Maximum reverse leakage current per leg		T _J = 125 °C	v _R = nateu v _R	140	IIIA	
Typical reverse leakage current	I _{RM} (1)	T _J = 125 °C	V _R = Rated V _R	89	mA	
Threshold Voltage	V _{F(TO)}	T. –T. maximum		0.37	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum		8.26	mΩ	
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal range	1220	pF		
Typical series inductance per leg	L _S	Measured lead to lead 5 mm	8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	

Note

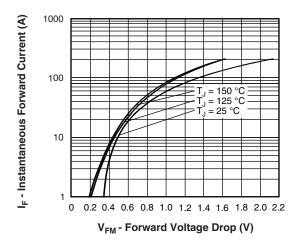
 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and stor temperature range	age	T _J , T _{Stg}		-55 to +150	°C	
Maximum thermal resistant junction to case per leg	e,	D	DC operation	2.0		
Maximum thermal resistance, junction to case per package		- R _{thJC}	De operation	1.0	°C/W	
Typical thermal resistance, case to heatsink			Mounting surface, smooth and greased	0.50		
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
Mounting torque minimum maximum				6 (5)	kgf · cm	
				12 (10)	(lbf · in)	
Marking device		Case style D ² PAK (TO-263AB)		48CTQ060S		
			Case style TO-262AA	48CTQ	060-1	



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1000

T_J = 150 °C

T_J = 125 °C

T_J = 75 °C

T_J = 25 °C

Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

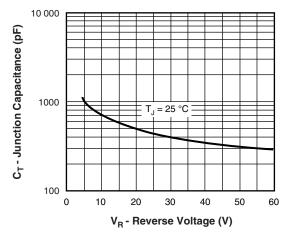


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

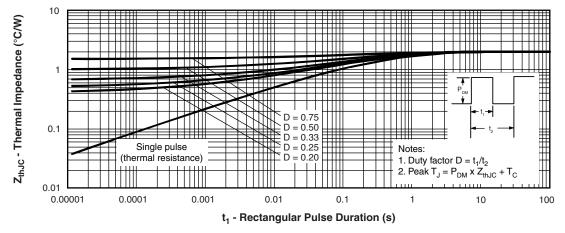


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)





Allowable Case Temperature (°C)

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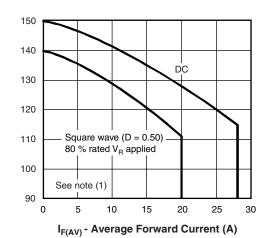


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

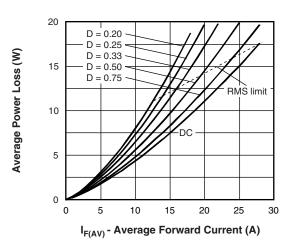


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

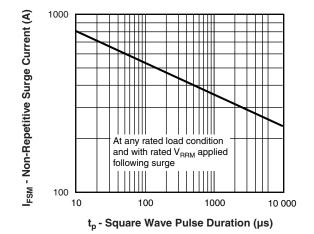


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

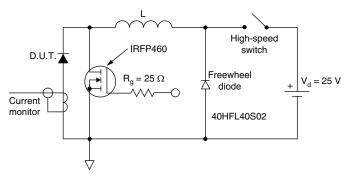


Fig. 8 - Unclamped Inductive Test Circuit

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = & \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = & \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D)}; I_R \text{ at } V_{R1} = 10 \text{ V}. \\ \end{array}$

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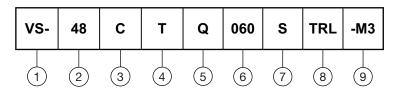


VS-48CTQ060S-M3, VS-48CTQ060-1-M3

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ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- 2 Current rating (40 A)
- Gircuit configuration: C = common cathode
- **4** T = TO-220
- 5 Schottky "Q" series
- Voltage rating (060 = 60 V)
- 7 • S = D²PAK (TO-263AB)
 - -1 = TO-262AA
- 8 • None = tube
 - TRL = tape and reel (left oriented for D²PAK (TO-263AB) only)
 - TRR = tape and reel (right oriented for D²PAK (TO-263AB) only)
- 9 -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-48CTQ060S-M3	50	Antistatic plastic tubes				
VS-48CTQ060STRL-M3	800	13" diameter plastic tape and reel				
VS-48CTQ060STRR-M3	800	13" diameter plastic tape and reel				
VS-48CTQ060-1-M3	50	Antistatic plastic tubes				

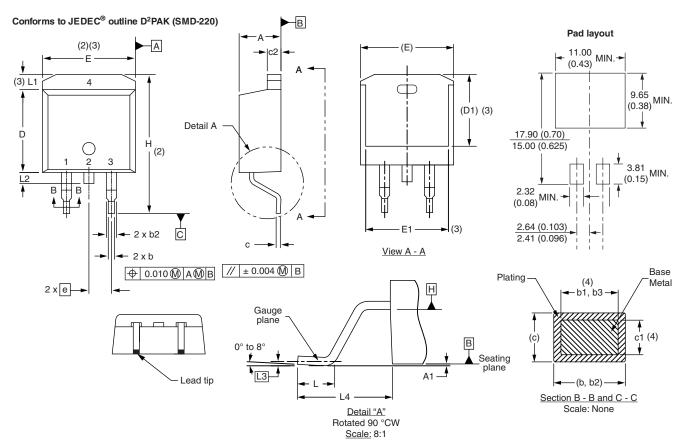
LINKS TO RELATED DOCUMENTS					
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164			
Differisions	TO-262AA	www.vishay.com/doc?96165			
Dout modeling information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444			
Part marking information	TO-262AA	www.vishay.com/doc?95443			
Packaging information		www.vishay.com/doc?96424			



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- $^{(1)}$ Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

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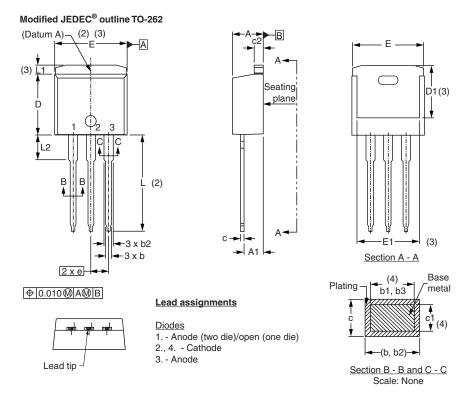




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TO-262

DIMENSIONS in millimeters and inches



CVMPOL	MILLIMETERS		INC	NOTES	
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.36	3.71	0.132	0.146	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

Revision: 11-Jul-2019 1 Document Number: 95419

Legal Disclaimer Notice



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